

60 V, 3A PNP low VCEsat (BISS) transistor

12 October 2015

Product data sheet

1. General description

PNP low V_{CEsat} Breakthrough in a Small Signal (BISS) transistor, encapsulated in an ultra thin DFN2020D-3 (SOT1061D) leadless small Surface-Mounted Device (SMD) plastic package with medium power capability and visible and soldarable side pads.

NPN complement: PBSS4360PAS

2. Features and benefits

- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability ${\sf I}_C$ and ${\sf I}_{CM}$
- High collector current gain (h_{FE}) at high I_C
- High efficiency due to less heat generation
- High temperature applications up to 175 °C
- Reduced Printed-Circuit Board (PCB) area requirements
- Leadless small SMD plastic package with soldarable side pads
- Exposed heat sink for excellent thermal and electrical conductivity
- Suitable for Automatic Optical Inspection (AOI) of solder joint
- AEC-Q101 qualified

3. Applications

- Loadswitch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

4. Quick reference data

Table 1. Qui	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	-60	V
I _C	collector current		-	-	-3	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	-6	А
R _{CEsat}	collector-emitter saturation resistance	I _C = -3 A; I _B = -300 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02 ; T _{amb} = 25 °C	-	87	150	mΩ



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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	3
2	E	emitter		1-1
3	С	collector	1 2 Transparent top view	2 sym013
			DFN2020D-3 (SOT1061D)	

6. Ordering information

Table 3. Ordering in	formation					
Type number	Package					
	Name	Description	Version			
PBSS5360PAS	DFN2020D-3	DFN2020D-3: plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body 2 x 2 x 0.65 mm	SOT1061D			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PBSS5360PAS	EA

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8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CBO}	collector-base voltage	open emitter		-	-80	V
V _{CEO}	collector-emitter voltage	open base		-	-60	V
V _{EBO}	emitter-base voltage	open collector		-	-8	V
I _C	collector current			-	-3	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-6	А
I _B	base current			-	-500	mA
I _{BM}	peak base current			-	-1	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.6	W
			[2][3]	-	1.2	W
			[4]	-	1.5	W
			[5][6]	-	2.5	W
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

^[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm².

[6] Device mounted on a ceramic PCB, AI_2O_3 , standard footprint.

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9. Thermal characteristics

Table 6.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ui(j-a)	thermal resistance	in free air	[1]	-	-	250	K/W
	from junction to		[<u>2][3]</u>	-	-	125	K/W
	ambient		[4]	-	-	100	K/W
			[5][6]	-	-	60	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

^[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[5] Device mounted on a ceramic PCB, Al_2O_3 , standard footprint.

^[6] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm².













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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V_{CB} = -64 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
current	current	V _{CB} = -64 V; I _E = 0 A; T _j = 150 °C	-	-	-50	μA
I _{CES}	collector-emitter cut-off current	V_{CE} = -48 V; V_{BE} = 0 V; T_{amb} = 25 °C	-	-	-100	nA
I _{EBO}	emitter-base cut-off current	V_{EB} = -6.4 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	$\label{eq:VCE} \begin{array}{l} V_{CE} = \textbf{-5} \; V; \; I_{C} = \textbf{-50} \; mA; \; pulsed; \\ t_{p} \leq 300 \; \mu s; \; \delta \leq 0.02 \; \; ; \; T_{amb} = 25 \; ^{\circ}C \end{array}$	150	250	-	
		V_{CE} = -5 V; I _C = -500 mA; pulsed;	130	220	-	
		$t_p \le 300 \ \mu s; \ \delta \le 0.02 \ ; \ T_{amb} = 25 \ ^\circ C$	120	200	-	
		$ \begin{aligned} &V_{CE} \texttt{=} \texttt{-5} V; \ I_{C} \texttt{=} \texttt{-2} A; \ pulsed; \\ &t_{p} \texttt{\leq} \texttt{300} \ \mu \texttt{s}; \ \breve{\delta} \texttt{\leq} \texttt{0.02} \ ; \ T_{amb} \texttt{=} \texttt{25} \ ^{\circ}C \end{aligned} $	100	160	-	
		V_{CE} = -5 V; I _C = -3 A; pulsed; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C	80	125	-	
OLOUI	collector-emitter saturation voltage	I_{C} = -0.5 A; I_{B} = -50 mA; pulsed; t_{p} ≤ 300 µs; δ ≤ 0.02 ; T_{amb} = 25 °C	-	-55	-100	mV
		I_{C} = -1 A; I_{B} = -100 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02 ; T_{amb} = 25 °C	-	-95	-170	mV
		I_{C} = -2 A; I_{B} = -200 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02 ; T_{amb} = 25 °C	-	-170	-320	mV
		$I_{\rm C}$ = -3 A; $I_{\rm B}$ = -300 mA; pulsed;	-	-260	-450	mV
R _{CEsat}	collector-emitter saturation resistance	$t_p \le 300 \ \mu s; \ \delta \le 0.02 \ ; \ T_{amb} = 25 \ ^\circ C$	-	87	150	mΩ
V _{BEsat}	base-emitter saturation voltage	$\begin{split} I_C &= -2 \text{ A}; I_B = -100 \text{ mA}; \text{ pulsed}; \\ t_p &\leq 300 \mu\text{s}; \delta &\leq 0.02 ; T_{amb} = 25 ^\circ\text{C} \end{split}$	-	-0.9	-1	V
V _{BEon}	base-emitter turn-on voltage	$\label{eq:Vce} \begin{split} V_{CE} &= -5 \text{ V; } I_C = -1 \text{ A; pulsed;} \\ t_p &\leq 300 \mu\text{s; } \delta \leq 0.02 ; T_{amb} = 25 ^\circ\text{C} \end{split}$	-	-0.8	-1	V
t _d	delay time	I _C = -2 A; I _{Bon} = -0.1 A; I _{Boff} = 0.1 A;	-	12	-	ns
tr	rise time	T _{amb} = 25 °C	-	95	-	ns
t _{on}	turn-on time		-	107	-	ns
s	storage time		-	160	-	ns
t _f	fall time		-	50	-	ns
off	turn-off time		-	210	-	ns
f _T	transition frequency	V _{CE} = -10 V; I _C = -100 mA; f = 100 MHz; T _{amb} = 25 °C	65	120	-	MHz

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11. Test information



This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBSS5360PAS v.1	20151012	Product data sheet	-	-			

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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